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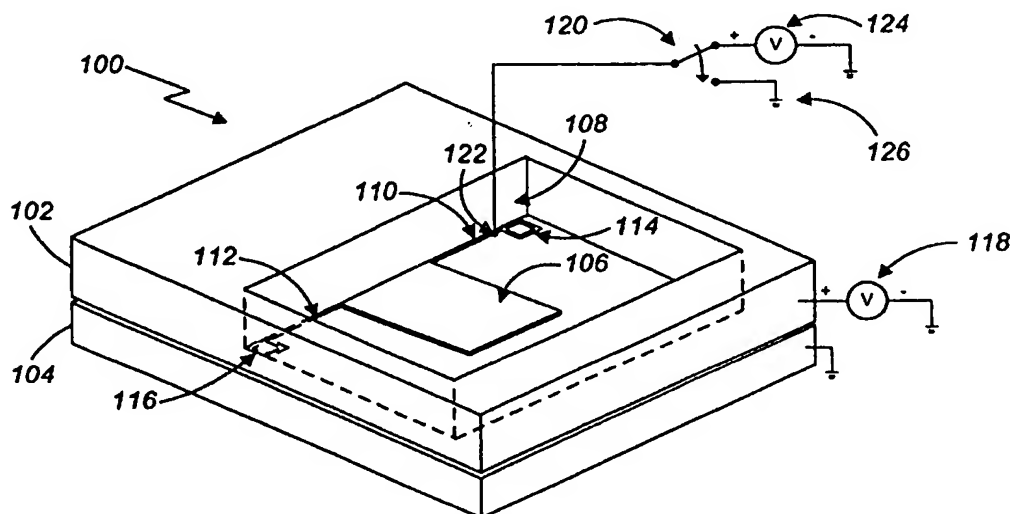
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(54) Title: CANTILEVERED MICROSTRUCTURE METHODS AND APPARATUS



(57) Abstract

Cantilevered microstructure apparatus and methods are described. An exemplary cantilevered microstructure apparatus includes a base, a cantilever, and a stop. The cantilever may be coupled to the base through a flexure, so that the cantilever is movable between a first angular orientation and a second angular orientation. The stop may be configured to contact the bottom portion of the cantilever in a contact area when the cantilever is in the second angular orientation. Alternatively, the stop may be configured to contact the cantilever in a contact area sized so that, upon application of an electrostatic bias between the cantilever and the stop, a sufficient force holds the cantilever against the stop. Alternatively, the stop may have a substantially planar surface configured to contact the cantilever in a contact area sized so that, upon application of a force to the cantilever substantially normal to the substantially planar surface of the stop, a sufficient force holds the cantilever against the stop such that the cantilever lies in a plane substantially parallel to the substantially planar surface of the stop.

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CANTILEVERED MICROSTRUCTURE METHODS AND APPARATUS

CROSS REFERENCE TO RELATED APPLICATIONS

This application claims the benefit of prior U.S. Provisional Application Serial
5 No. 60/123,496, filed March 9, 1999.

STATEMENT AS TO FEDERALLY SPONSORED RESEARCH

This invention was made with Government support under Grant No. DABT 63-
95-C-0055, which was awarded by the Defense Advanced Research Projects Agency
10 (DARPA). The Government has certain rights in this invention.

BACKGROUND OF THE INVENTION

The present invention relates to cantilevered microstructure methods and
apparatus. Cantilevered microstructures may be used in many different applications. For
15 example, certain cantilevered microstructures may be used to implement large-port-count
optical crossbar switches which facilitate the flow of data over a computer network (e.g.,
the Internet).

The explosive growth of internet traffic in the last few years, and its unabated
continuation into the foreseeable future, has created an unprecedented demand on the
20 communication infrastructure of both long distance and interchange carriers. The term
"fiber exhaust" was coined in the last few years to describe the saturation of traffic in the
present installed base of optical fibers. Thus ushered in the era of wavelength division
multiplex (WDM), a technique for using multiple colors of light inside a single strand of
fiber in order to boost the capacity of the fiber manifold without actually having to install
25 any new fibers. But as internet traffic continues to grow, the fiber-optic network
infrastructure is encountering another bottleneck which WDM or similar solutions cannot
solve. Interconnection between the growing number of channels supported by WDM
systems demands solutions based on optical-cross-connects (OXCs). Large-port-count
optical crossbar switches promise to be key components for performing OXC functions.

30 An optical crossbar switch can provide interchange of data paths between
different fibers, at multi-gigabit data rates, without having to first convert them into the

electronic domain as is being done in existing networks. An NxN optical crossbar switch consists of N input and N output optical fiber ports, with the capability of selectively directing light from any input port to any output port in a "non-blocking" fashion.

Currently, switches deployed in the communication infrastructure operate by converting
5 the input optical signals to electronic signals, directing the electronic signals to the proper output channels, and converting them back into optical signals. In an all-optical OXC, the light is directly deflected from an input fiber port into an output fiber port without any electrical conversion. Each of the optical beams can be expanded and collimated by inserting a microlens at the tip of each input and output fiber port. By propagating an
10 array of optical beams in free space and selectively actuating reflectors in an array of movable reflectors, any one of the N input optical beams can be directed to any one of the N output fibers ports. The core of each input and output fiber port is the region in which most of the optical beam travels. Due to the small diameter of the core, the optical crossbar switch requires the reflectors to be maintained at a precise position in order to
15 direct each optical beam from one fiber port to another.

The optical crossbar switch has several inherent advantages over its electronic counterpart, including data rate, format, wavelength independence, and lower costs. Furthermore, with advances in microelectromechanical systems (MEMS) technology, batch-processing and assembly methods similar to those used in the IC industry can be
20 employed to produce optical crossbar switches with high port-counts at very low costs.

SUMMARY OF THE INVENTION

In one aspect, the invention features a cantilevered microstructure apparatus comprising a base, a cantilever having a bottom portion coupled to the base so that the
25 cantilever is movable between a first angular orientation and a second angular orientation, and a stop configured to contact the bottom portion of the cantilever in a contact area when the cantilever is in the second angular orientation.

In another aspect, the invention features a cantilevered microstructure apparatus comprising a base, a cantilever coupled to the base and movable between a first angular
30 orientation and a second angular orientation, and a stop configured to contact the cantilever in a contact area sized so that, upon application of an electrostatic bias between the cantilever and the stop, a sufficient force holds the cantilever against the stop.

Embodiments may include one or more of the following features.

The cantilever can be coupled to the base at an anchor location. The cantilever can be coupled to the base through a flexure. The flexure may be formed from a flexible and resilient

- 5 material accommodating changes in the angular orientation of the cantilever about the anchor location with respect to the first angular orientation, and a lateral position of the cantilever with respect to the anchor location. The cantilever and the stop may each comprise a respective electrically conductive portion. Upon application of a magnetic field, the cantilever may move to the second angular orientation and contact the stop in a
10 contact area characterized by a height b and a width w that satisfies the following condition:

$$\frac{\epsilon w V^2}{2g^2} \times \frac{b^2 + 2ab}{2} \geq k_\theta \theta \quad (1)$$

- where ϵ is a constant representing the permittivity of a material separating the electrically conductive portion of the cantilever and the electrically conductive portion of the stop
15 when the cantilever is in contact with the stop, V is a voltage applied to create an electrostatic bias between the cantilever and the stop, g is a distance separating the electrically conductive portion of the cantilever and the electrically conductive portion of the stop when the cantilever is in contact with the stop, k_θ is a torsional spring constant of the flexure, θ is the angular orientation of the cantilever about the anchor location with
20 respect to the first angular orientation, and a is a distance separating the stop and the base. If the second angular orientation is an obtuse angle about the anchor location with respect to the first angular orientation, the cantilever may move to the second angular orientation and contact the stop in a contact area characterized by a height b and a width w provided two conditions are satisfied: (i) condition 1 defined above; and (ii) the following
25 condition:

$$\frac{\epsilon w V^2}{2g^2} \times \frac{b^2}{2} \geq kd(a+b) \quad (2)$$

where k is a lateral spring constant of the flexure, and d is a distance separating the anchor location and a plane defined by the contact area of the stop. Alternatively, if the second angular orientation is an obtuse angle about the anchor location with respect to the first angular orientation, the cantilever may move to the second angular orientation and contact the stop in a contact area characterized by a height b and a width w provided two conditions are satisfied: (i) condition 1 defined above; and (ii) the following condition:

$$\frac{\epsilon w V^2}{2g^2} \times \frac{b^2}{2} \geq kda \quad (3)$$

where k is a lateral spring constant of the flexure, and d is a distance separating the anchor location and a plane defined by the contact area of the stop.

The flexure may be formed from polycrystalline-silicon. The contact area may comprise a substantially planar surface configured to define a lateral position of the cantilever with respect to an anchor location and the second angular orientation of the cantilever about the anchor location with respect to the first angular orientation when a force is applied between the cantilever and the stop. The substantially planar contact area surface may be substantially perpendicular to a top surface of the base. The force may be an electrostatic force. The base, the cantilever and the stop may be formed from a semiconductor material. The cantilever may have a current-carrying coil, a hard magnetic material, a soft magnetic material, or a combination of the three. The cantilever may have a light-reflecting surface. The cantilever may be one of an array of cantilevers coupled to the base, each cantilever having a respective stop configured to contact the cantilever in a contact area.

In another aspect, the invention features a cantilevered microstructure apparatus comprising a base, a cantilever coupled to the base and movable between a first position and a second position, and a stop having a substantially planar surface configured to contact the cantilever in a contact area sized so that, upon application of a force to the cantilever substantially normal to the substantially planar surface of the stop, a sufficient force holds the cantilever against the stop such that the cantilever lies in a plane substantially parallel to the substantially planar surface of the stop.

In yet another aspect, the invention features a method for directing an optical beam from a first port to a second port. The method comprises applying a first force to a cantilever to move the cantilever from a first angular orientation to a second angular orientation, wherein the cantilever contacts a stop in the second angular orientation, and
5 applying a second force between the cantilever and the stop to hold the cantilever against the stop in a plane substantially parallel to a substantially planar surface of the stop, such that the cantilever directs an optical beam from a first port to a second port. The first force may be a magnetic field; the second force may be an electrostatic bias.

In yet another aspect, the invention features a method for directing an optical
10 beam from a first port to a second port using a light-reflective cantilever having a first angular orientation in the absence of an applied force and a static equilibrium position in the presence of a steady force. The method comprises applying a first force to the cantilever to move the cantilever from the first angular orientation to a second angular orientation other than the static equilibrium position, wherein the cantilever contacts a
15 stop in the second angular orientation, and applying a second force between the cantilever and the stop to hold the cantilever against the stop in a plane substantially parallel to a substantially planar surface of the stop, such that the cantilever directs an optical beam from a first port to a second port.

Embodiments may include one or more of the following features.

20 The first force may be a time-varying force. The first force may have a profile selected from a group consisting of a step profile, a ramp profile, a sinusoidal profile, and a pulse profile. The first force may be a magnetic field. The second force may be an electrostatic bias.

In yet another aspect, the invention features a method for manufacturing an
25 apparatus for directing optical beams. The method comprises coupling an array of cantilevers to a base assembly, each cantilever being movable between a first angular orientation and a second angular orientation, and forming an array of apertures in a stop assembly, the stop assembly being coupled to the base assembly, and each aperture being
30 positioned to contact its respective cantilever when the cantilever is in the second angular orientation.

Embodiments may include one or more of the following features.

Each aperture may be constructed to have at least one substantially planar sidewall constructed to lie in a plane orthogonal to a top surface of the base assembly. Each cantilever may be coupled to the base assembly through at least one flexure.

Advantages that can be seen in implementations of the invention include one or more of the following. The invention can produce an optical crossbar switch having very low insertion loss. The precise positioning of the reflectors enabled by the invention can be used in applications that integrate micro-optical elements, for example, lasers, lenses, movable reflectors and beam splitters, on a silicon chip.

The details of one or more embodiments of the invention are set forth in the accompanying drawings and the description below. Other features and advantages of the invention will become apparent from the following description, including the drawings and the claims.

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 is a diagrammatic perspective view of a cantilevered microstructure apparatus.

FIG. 2a is a diagrammatic top view of a cantilever having a different lateral position with respect to an anchor location and a different angular orientation about an anchor location with respect to a first angular orientation.

FIG. 2b is a diagrammatic side view of a cantilever having a different lateral position with respect to an anchor location and a different angular orientation about an anchor location with respect to a first angular orientation.

FIGS. 3a-3f are diagrammatic perspective views of the cantilevered microstructure apparatus of FIG. 1 upon application of various combinations of a magnetic field and an electrostatic bias.

FIG. 4a is a diagrammatic side view of a cantilevered microstructure apparatus, where a base and a stop have a slight misalignment.

FIG. 4b is a diagrammatic side view of the cantilevered microstructure apparatus of FIG. 4a upon application of a magnetic field.

FIG. 4c is a diagrammatic side view of the cantilevered microstructure apparatus of FIG. 4a upon application of an electrostatic bias between the cantilever and the stop.

FIG. 4d is a diagrammatic front view of the cantilevered microstructure apparatus of FIG. 4c.

FIG. 5a is a diagrammatic side view of a cantilevered microstructure apparatus, where a base and a stop have a slight misalignment.

5 FIG. 5b is a diagrammatic side view of the cantilevered microstructure apparatus of FIG. 5a upon application of a magnetic field.

FIG. 5c is a diagrammatic side view of the cantilevered microstructure apparatus of FIG. 5a upon application of an electrostatic bias between the cantilever and the stop.

10 FIG. 6a is a diagrammatic perspective view of an N x M system cantilevered microstructure apparatus used as an optical switch.

FIG. 6b is a diagrammatic top view of the N x M system cantilevered microstructure apparatus of FIG. 6a.

FIG. 7a is a diagrammatic side view of the cantilevered microstructure apparatus of FIG. 1 upon application of a magnetic field, where the magnetic field is not parallel to a sidewall of a stop.

FIG. 7b is a diagrammatic front view of an alternate embodiment of a cantilevered microstructure apparatus.

20 FIG. 7c is a diagrammatic side view of the cantilevered microstructure apparatus of FIG. 7b upon application of a magnetic field, where the magnetic field is not parallel to a sidewall of a stop.

Like reference numbers and designations in the various drawings indicate like elements.

DETAILED DESCRIPTION

25 FIG. 1 shows an apparatus 100 having a stop 102, a base 104 and a cantilever 106. The cantilever 106 is coupled to the base 104 and is movable between a first angular orientation and a second angular orientation. The stop 102 has at least one substantially planar sidewall 108 that is configured to contact the cantilever 106 in a contact area when the cantilever 106 is in the second angular orientation. In one implementation, a
30 substantially planar sidewall 108 is constructed to lie in a plane which is orthogonal to the top surface of the base 104.

The apparatus 100 is fabricated by a MEMS process. The base 104 may be composed of an insulating layer disposed over a semiconductor substrate; for example, silicon nitride, silicon oxide, or a combination of both, may be disposed over a silicon substrate. The cantilever 106 may be a rectangular beam formed from a conductive material or a semiconductive material such as polycrystalline silicon. A layer of magnetic material may be plated onto the cantilever 106. More than one region of the cantilever 106 may be so plated. The magnetic material may be one of various combinations of nickel, iron, or other elements, and is usually ferromagnetic characterized by a high saturation magnetization.

The cantilever 106 may be coupled through flexures 110 and 112 to the base 104 at anchor locations. In one implementation, insulative anchors 114 and 116 are used to attach the flexures 110 and 112 to the base 104. The flexures 110 and 112 may be formed from a flexible and resilient conductive or semiconductive material (e.g., polycrystalline silicon). The flexible material provides the flexures 110 and 112 with a degree of elasticity. The flexures 110 and 112 allow the cantilever 106 to change its angular orientation about the anchors 114 and 116 with respect to the first angular orientation and its lateral position with respect to the anchors 114 and 116, as shown in FIGS. 2a and 2b.

In one implementation, the stop 102 is coupled to a voltage source 118 and the base 104 is electrically grounded. An electrostatic clamping circuit can be formed from a switch 120, a contact 122 for forming a connection between the switch 120 and the flexure 110, the cantilever 106, the flexure 112, and the anchor 116, and is switchable between a voltage source 124 and electrical ground 126. The voltage sources 118 and 124 may be external sources such as power supplies or batteries, or internal sources on the apparatus 100. An electrostatic bias can be created between the cantilever 106 and one of the clamping surfaces (base 104 and stop 102) depending on the position of the switch 120.

Referring to FIG. 3a, in the absence of any applied force, the cantilever 106 lies in the first angular orientation substantially parallel to the base 104. The voltage source 124 may be coupled to the electrostatic clamping circuit to create an electrostatic bias between the cantilever 106 and the base 104 upon application of a voltage V_1 . If a sufficient voltage V_1 is applied, the cantilever 106 is "clamped" to the base 104 and restrains the cantilever 106 from rotating in the presence of an applied force, for example,

a magnetic field 126 as shown in FIG. 3b. If the cantilever 106 is not clamped to the base 104, application of the magnetic field 126 would cause the cantilever 106 to be rotated about the anchors 114 and 116 between the first angular orientation and the second angular orientation until there is an equilibrium between the resultant torque from the torsional stretching of the flexures 110 and 112 and the force on the cantilever 106 caused by the magnetic field 126. The angular orientation of the cantilever 106 at the equilibrium point defines a static equilibrium position. In one implementation, the static equilibrium position is the second angular orientation, as shown in FIG. 3c. In another implementation, the static equilibrium position is between the first angular orientation and the second angular orientation, as shown in FIG. 3d. In this implementation, the force on the cantilever 106 resulting from the application of the magnetic field 126 can be time-varying, such that the cantilever 106 is provided with a momentum that rotates the cantilever 106 beyond the static equilibrium position to the second angular orientation. The time-varying force on the cantilever 106 may have a step profile, a ramp profile, a sinusoidal profile or a pulse profile. Once the cantilever 106 is in the second angular orientation, an electrostatic bias may be created between the cantilever 106 at electrical ground and the stop 102 having a voltage V2, as shown in FIG. 3e. The cantilever 106 clamps to the sidewall 108 in a contact area characterized by a height b and a width w provided the following condition is satisfied:

20

$$\begin{array}{ll} \text{torque about axis defined through anchors} & \text{torque resulting from} \\ \text{torsional} & \\ \text{114 and 116 resulting from electrostatic bias} & \geq \text{stretching of flexures 110 and} \\ \text{112} & \\ \text{created between cantilever 106 and stop 102} & \end{array}$$

25

$$\frac{\epsilon w V^2}{2g^2} \times \frac{b^2 + 2ab}{2} \geq k_\theta \theta \quad (1)$$

where ϵ is a constant representing the permittivity of a material separating the electrically conductive portion of the cantilever 106 and the electrically conductive portion of the stop 102 when the cantilever 106 is in contact with the stop 102, V is a voltage applied to create an electrostatic bias between the cantilever 106 and the stop 102, g is a distance

separating the electrically conductive portion of the cantilever 106 and the electrically conductive portion of the stop 102 when the cantilever 106 is in contact with the stop 102, k_0 is a torsional spring constant of the flexures 110 and 112, θ is the angular orientation of the cantilever 106 about the anchors 114 and 116 with respect to the first angular orientation, and a is a distance separating the stop 102 and the base 104. Once the cantilever 106 is clamped to the sidewall 108, removing the magnetic field 126 has no effect on the angular orientation of the cantilever 106, as shown in FIG. 3f.

FIG. 4a shows the stop 102 coupled to the base 104 with a slight misalignment. In this example, the anchors 114 and 116 are offset from a plane 402 defined through the contact area of stop 102. The cantilever 106 is movable through an obtuse angle θ about the anchors 114 and 116 with respect to the first angular orientation. In the absence of an applied force, the cantilever 106 lies in the first angular orientation substantially parallel to the base 102. If the cantilever 106 is not clamped to the base 104, application of the magnetic field 126 may rotate the cantilever 106 about the anchors 114 and 116 until the cantilever 106 contacts a top edge 128 of the stop 102 in the second angular orientation, as shown in FIG. 4b. The cantilever 106 clamps to the sidewall 108 in a contact area characterized by a height b and a width w as shown in FIGS. 4c and 4d provided two conditions are satisfied: (i) condition 1 defined above; and (ii) the following condition:

torque about axis defined through top lateral edge 128 resulting from electrostatic bias created between cantilever 106 and stop 102 \geq torque resulting from the stretching of flexures 110 and 112

$$\frac{\epsilon w V^2}{2g^2} \times \frac{b^2}{2} \geq kd(a+b) \quad (2)$$

where k is a lateral spring constant of the flexures 110 and 112, and d is a distance separating the location of the anchors 114 and 116 and a plane defined by the contact area 404 of the stop 102.

FIG. 5a shows the stop 102 coupled to the base 104 with an alternative misalignment. In this example, the anchors 114 and 116 are offset from a plane 502 defined through the contact area of the stop 102. The cantilever 106 is movable through an acute angle θ about the anchors 114 and 116 with respect to the first angular orientation. In the absence of an applied force, the cantilever 106 lies in the first angular orientation substantially parallel to the base 102. If the cantilever 106 is not clamped to the base 104, application of the magnetic field 126 may rotate the cantilever 106 about the anchors 114 and 116 until the cantilever 106 contacts a bottom edge 130 of the stop 102 in the second angular orientation, as shown in FIG. 5b. The cantilever 106 clamps to the sidewall 108 in a contact area characterized by a height b and a width w as shown in FIG. 5c provided two conditions are satisfied: (i) condition 1 defined above; and (ii) the following condition:

torque about axis defined through bottom lateral edge 130 resulting from electrostatic bias \geq torque resulting from the stretching of flexures 110 and 112 created between cantilever 106 and stop 102

$$\frac{\epsilon w V^2}{2g^2} \times \frac{b^2}{2} \geq kda \quad (3)$$

In the three cases described above and shown in FIGS. 3f, 4c and 5c, in the absence of an applied force, the cantilever 106 returns to the first angular orientation substantially parallel to the base 104 as the torsional and lateral stretching of the flexures 110 and 112 are relaxed.

FIGS. 6a and 6b show an apparatus 600 having a stop assembly 602 coupled to a base assembly 604. The base assembly 604 has an array of cantilevers 606. Each cantilever is coupled to the base assembly 604 by at least one flexure which permits each cantilever to change its angular orientation and lateral position. The stop assembly 602 may have an array of substantially planar surfaces. Each substantially planar surface may be configured to contact a respective cantilever in a contact area sized so that, upon application of a force to the cantilever substantially normal to the substantially planar

surface of the stop assembly 602, a sufficient force holds the cantilever against the stop assembly 602 in a plane substantially parallel to the substantially planar surface of the stop assembly 602. In one implementation, the stop assembly 602 defines an array of apertures 608, as shown in FIG. 6a. Each aperture has at least one substantially planar surface 610 that contacts a respective cantilever in a contact area. Each substantially planar surface 610 is constructed to lie in a plane normal to the base assembly 604. The array of cantilevers 606 may be coupled to an electrostatic clamping circuit such that each cantilever may be individually selected to be clamped to its respective surface 610 or to the base assembly 604. In an alternative implementation (not shown), the stop assembly may define an array of cavities, each cavity having at least one substantially planar surface that contacts a respective cantilever in a contact area.

One application of the apparatus 600 is an optical switch. In one implementation, the array of cantilevers 606 act as reflectors. A suitable reflector coating may be deposited on the portion of each cantilever above the plane of a top surface 612 of the stop assembly 602 to enhance reflectivity if desired. In an alternative implementation, the array of cantilevers 606 act as beam splitters. Each cantilever may be constructed from a material that transmits and reflects different parts of an optical beam. Each cantilever is similarly sized and constructed such that each sidewall 610 contacts a bottom portion of its respective cantilever.

FIG. 6a shows the apparatus 600 having three optical inputs 614, 616, and 618, and three optical outputs 620, 622, and 624. The N inputs (614, 616, and 618) are along one side of the apparatus 600 and the M outputs (620, 622, and 624) are along an adjacent side. The switching elements are the array of cantilevers 606. Each cantilever is oriented at a similar angle, for example, 45 degrees to an incoming optical beam. If the mth cantilever along one of the N input beams is clamped to its respective sidewall, that beam is reflected into the mth of the M outputs. All but one cantilever in a given input line is held down by the electrostatic bias applied between the cantilever and the base assembly 604. The cantilever that is clamped to its respective sidewall selects the output for that input line.

The materials from which the apparatus 600 is fabricated, the voltage sources, the applied electrostatic bias, and the applied magnetic fields may be chosen by a user to adjust the sensitivity of the apparatus 600 for any particular purpose or application. The

apparatus 600 may be fabricated using techniques including "lithographie, galvanofornung and abformung" (LIGA), traditional machining, deep anisotropic plasma etching and laser machining. The stop assembly 602 may be fabricated by anisotropic etching of (110)-oriented silicon which ensures the angular uniformity of all the sidewalls 610 on the stop assembly 602. The array of cantilevers 606, sidewalls 610 and the base assembly 604 may be fabricated to have textured surfaces on one or more surfaces to reduce sticking when each cantilever is clamped to its respective sidewall or to the base assembly 604. The textured surface may include dimples, bumps, and ridges. The number of cantilevers defining the N-by-M array of cantilevers 606 may be adjusted based on the application of the apparatus 600. The apparatus 600 may be fabricated in a single batch-process and consist of a single stop-base module. Alternatively, the apparatus 600 may be fabricated in a two-part process, one process for fabricating the stop assembly 602 and the other process for fabricating the base assembly 604. The stop assembly 602 may be aligned with the base assembly 604 in a separate alignment step.

The applied electrostatic bias may be an attractive force applied by the electrostatic clamping circuit described above or by other means, where the attractive force is defined as any force that pushes or pulls a cantilever towards a stop.

The magnetic fields may be applied using coils located internal or external to the apparatus 600, or a permanent magnet located internal or external to the apparatus 600. Currentcarrying coils, hard magnetic materials, soft magnetic materials, or a combination of the three formed on each of the array of cantilevers 606 may apply a force to the cantilever in the presence of magnetic fields. An applied magnetic field 702 that is not perfectly parallel to the sidewall 704 may induce a slight torque and resultant bending in the portion of the cantilever 706 containing a reflective surface when the cantilever 706 is clamped to the sidewall 704, as shown in FIG. 7a. The resultant bending may cause a misalignment of a reflected beam. FIG. 7b shows an alternative implementation to the cantilever 706 that reduces the bending effects on optical performance. The magnetic portion 708 of the cantilever 710 is connected to the rest of the cantilever 710 by support arms 712. The support arms 712 isolate the portion of the cantilever 710 containing a reflective surface 714 from the magnetic field 702 that is applied on the magnetic portion 708 of the cantilever 710. In this implementation, when the cantilever 710 is clamped to the sidewall 716, application of the magnetic field 702 that is not perfectly parallel to the

sidewall 716 results in minimal bending in the portion of the cantilever 710 containing the reflective surface 714 as shown in FIG. 7c.

The invention has been described in terms of particular embodiments. Other embodiments are within the scope of the following claims. For example, the steps of the
5 invention can be performed in a different order and still achieve desirable results.

WHAT IS CLAIMED:

1. An apparatus, comprising:
 - a base;
 - 5 a cantilever having a bottom portion coupled to the base so that the cantilever is movable between a first angular orientation and a second angular orientation; and
 - a stop configured to contact the bottom portion of the cantilever in a contact area when the cantilever is in the second angular orientation.
2. An apparatus, comprising:
 - 10 a base;
 - a cantilever coupled to the base and movable between a first angular orientation and a second angular orientation; and
 - a stop configured to contact the cantilever in a contact area sized so that, upon application of an electrostatic bias between the cantilever and the stop, a sufficient force
 - 15 holds the cantilever against the stop.
3. The apparatus of claims 1 or 2, wherein the cantilever is coupled to the base at an anchor location.
4. The apparatus of claim 3, wherein the cantilever is coupled to the base through a flexure.
- 20 5. The apparatus of claim 4, wherein the flexure is formed from a flexible and resilient material accommodating changes in:
 - the angular orientation of the cantilever about the anchor location with respect to the first angular orientation; and
 - a lateral position of the cantilever with respect to the anchor location.
- 25 6. The apparatus of claim 5, wherein the cantilever and the stop each comprises a respective electrically conductive portion.
7. The apparatus of claim 6, wherein:
 - upon application of a magnetic field, the cantilever moves to the second angular orientation and contacts the stop in a contact area characterized by a height b and a width
 - 30 w that satisfies the following condition:

$$\frac{\epsilon w V^2}{2g^2} \times \frac{b^2 + 2ab}{2} \geq k_\theta \theta$$

- where ϵ is a constant representing the permittivity of a material separating the electrically conductive portion of the cantilever and the electrically conductive portion of the stop when the cantilever is in contact with the stop, V is a voltage applied to create an electrostatic bias between the cantilever and the stop, g is a distance separating the electrically conductive portion of the cantilever and the electrically conductive portion of the stop when the cantilever is in contact with the stop, k_0 is a torsional spring constant of the flexure, θ is the angular orientation of the cantilever about the anchor location with respect to the first angular orientation, and a is a distance separating the stop and the base.
8. The apparatus of claim 7, wherein the cantilever contacts the stop in a contact area characterized by a height b and a width w that further satisfies the following condition when the second angular orientation is an obtuse angle about the anchor location with respect to the first angular orientation:

$$\frac{\epsilon w V^2}{2g^2} \times \frac{b^2}{2} \geq kd(a+b)$$

- where k is a lateral spring constant of the flexure, and d is a distance separating the anchor location and a plane defined by the contact area of the stop.
9. The apparatus of claim 7, wherein the cantilever contacts the stop in a contact area characterized by a height b and a width w that further satisfies the following condition when the second angular orientation is an acute angle about the anchor location with respect to the first angular orientation:

$$\frac{\epsilon w V^2}{2g^2} \times \frac{b^2}{2} \geq kda$$

- where k is a lateral spring constant of the flexure, and d is a distance separating the anchor location and a plane defined by the contact area of the stop.
10. The apparatus of claim 5, wherein the flexure is formed from polycrystalline-silicon.
11. The apparatus of claim 1, wherein the contact area comprises a substantially planar

surface configured to define a lateral position of the cantilever with respect to an anchor location and the second angular orientation of the cantilever about the anchor location with respect to the first angular orientation when a force is applied between the cantilever and the stop.

- 5 12. The apparatus of claim 11, wherein the substantially planar contact area surface is substantially perpendicular to a top surface of the base.
13. The apparatus of claim 11, wherein the force is an electrostatic force.
14. The apparatus of claims 1 or 2, wherein the base, the cantilever and the stop are formed
- 10 from a semiconductor material.
15. The apparatus of claims 1 or 2, wherein the cantilever comprises a current-carrying coil.
16. The apparatus of claims 1 or 2, wherein the cantilever comprises a hard magnetic material.
- 15 17. The apparatus of claims 1 or 2, wherein the cantilever comprises a soft magnetic material.
18. The apparatus of claims 1 or 2, wherein the cantilever comprises a light-reflecting surface.
19. The apparatus of claims 1 or 2, wherein the cantilever is one of an array of
- 20 cantilevers coupled to the base, each cantilever having a respective stop configured to contact the cantilever in a contact area.
20. An apparatus, comprising:
- a base;
- a cantilever coupled to the base and movable between a first position and a second
- 25 position; and
- a stop having a substantially planar surface configured to contact the cantilever in a contact area sized so that, upon application of a force to the cantilever substantially normal to the substantially planar surface of the stop, a sufficient force holds the cantilever against the stop such that the cantilever lies in a plane substantially parallel to
- 30 the substantially planar surface of the stop.
21. The apparatus of claim 20, wherein the cantilever is coupled to the base at an anchor location.

22. The apparatus of claim 21, wherein the cantilever is coupled to the base through a flexure.
23. The apparatus of claim 22, wherein the flexure is formed from a flexible and resilient material accommodating changes in:
- 5 an angular orientation of the cantilever about the anchor location with respect to the first position; and
- a lateral position of the cantilever with respect to the anchor location.
24. The apparatus of claim 23, wherein the flexure is formed from polycrystalline-silicon.
- 10 25. The apparatus of claim 20, wherein the substantially planar surface is substantially perpendicular to a top surface of the base.
26. The apparatus of claim 20, wherein the base, the cantilever and the stop are formed from a semiconductor material.
27. The apparatus of claim 20, wherein the cantilever comprises a current-carrying coil.
- 15 28. The apparatus of claim 20, wherein the cantilever comprises a hard magnetic material.
29. The apparatus of claim 20, wherein the cantilever comprises a soft magnetic material.
30. The apparatus of claim 20, wherein the cantilever comprises a light-reflecting surface.
- 20 31. The apparatus of claim 20, wherein the cantilever is one of an array of cantilevers coupled to the base, each cantilever having a respective stop configured to contact the cantilever in a contact area.
32. A method for directing an optical beam from a first port to a second port comprising:
- applying a first force to a cantilever to move the cantilever from a first angular
- 25 orientation to a second angular orientation, wherein the cantilever contacts a stop in the second angular orientation; and
- applying a second force between the cantilever and the stop to hold the cantilever against the stop in a plane substantially parallel to a substantially planar surface of the stop, such that the cantilever directs an optical beam from a first port to a second port.
- 30 33. The method of claim 32, wherein the first force is a magnetic field.
34. The method of claim 32, wherein the second force is an electrostatic bias.

35. A method for directing an optical beam from a first port to a second port using a light-reflective cantilever having a first angular orientation in the absence of an applied force and a static equilibrium position in the presence of a steady force, the method comprising:

5 applying a first force to the cantilever to move the cantilever from the first angular orientation to a second angular orientation other than the static equilibrium position, wherein the cantilever contacts a stop in the second angular orientation; and

 applying a second force between the cantilever and the stop to hold the cantilever against the stop in a plane substantially parallel to a substantially planar surface of the stop, such that the cantilever directs an optical beam from a first port to a second port.

10 36. The method of claim 35, wherein the first force is a time-varying force.

37. The method of claim 36, wherein the first force has a profile selected from a group consisting of a step profile, a ramp profile, a sinusoidal profile, and a pulse profile.

38. The method of claim 35, wherein the first force is a magnetic field.

15 39. The method of claim 35, wherein the second force is an electrostatic bias.

40. A method for manufacturing an apparatus for directing optical beams, comprising:

 coupling an array of cantilevers to a base assembly, each cantilever being movable between a first angular orientation and a second angular orientation; and

 forming an array of apertures in a stop assembly, the stop assembly being coupled to the base assembly, and each aperture being positioned to contact its respective cantilever when the cantilever is in the second angular orientation.

20 41. The method of claim 40, wherein each aperture is constructed to have at least one substantially planar sidewall constructed to lie in a plane orthogonal to a top surface of the base assembly.

25 42. The method of claim 40, wherein each cantilever is coupled to the base assembly through at least one flexure.

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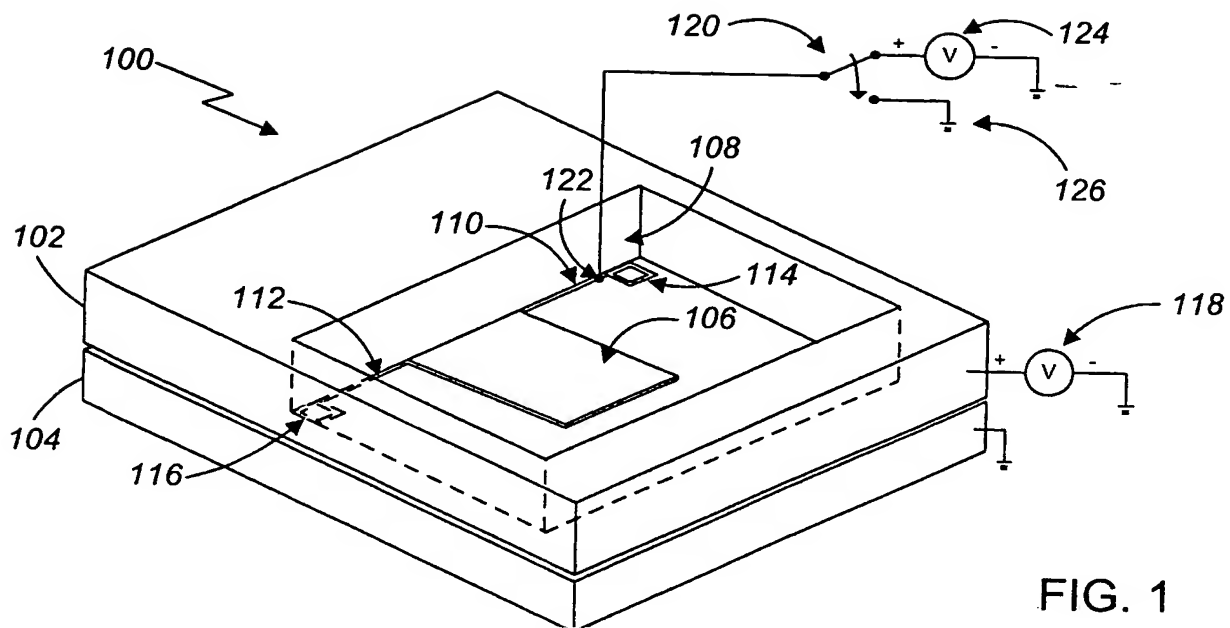


FIG. 1

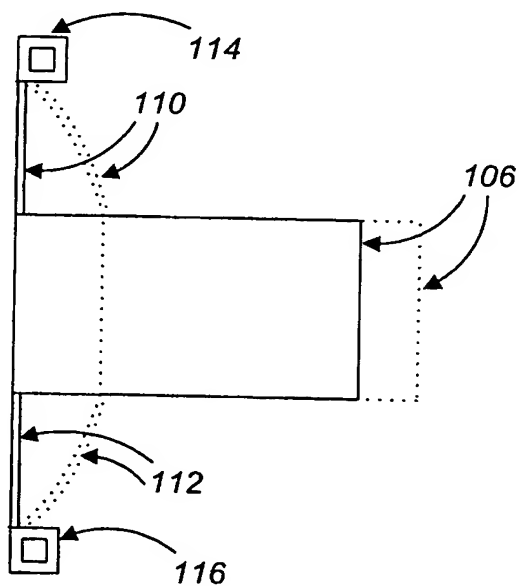


FIG. 2a
(top view)

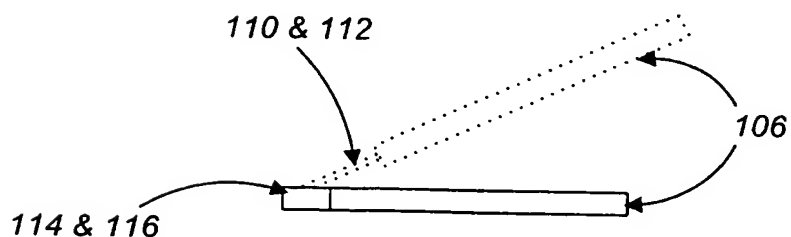
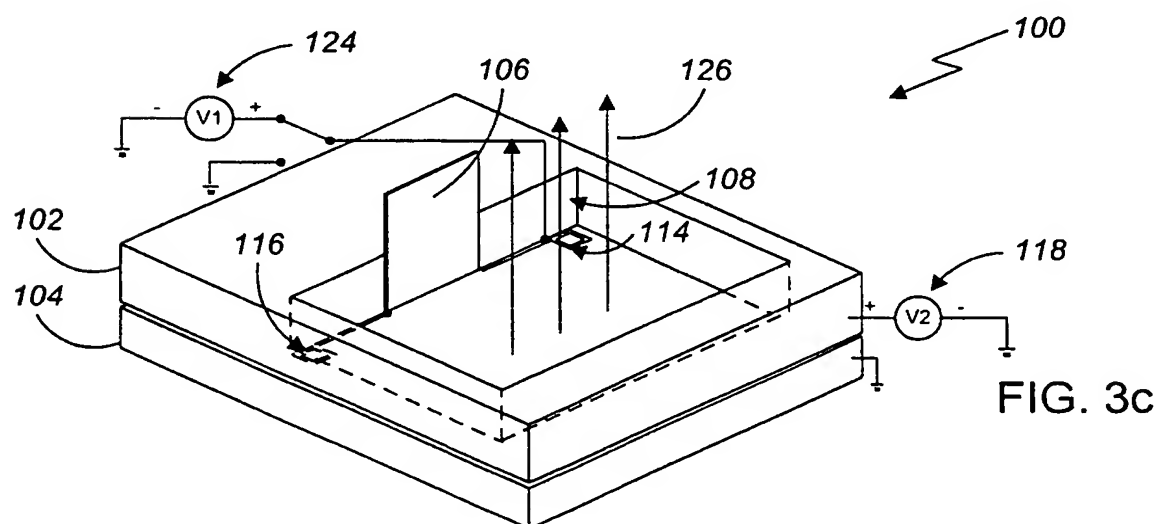
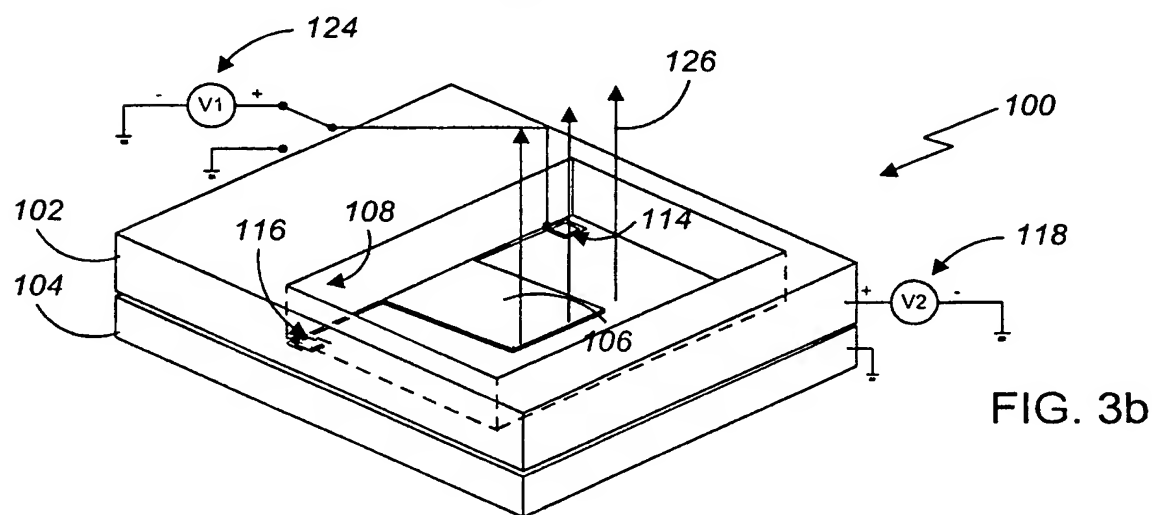
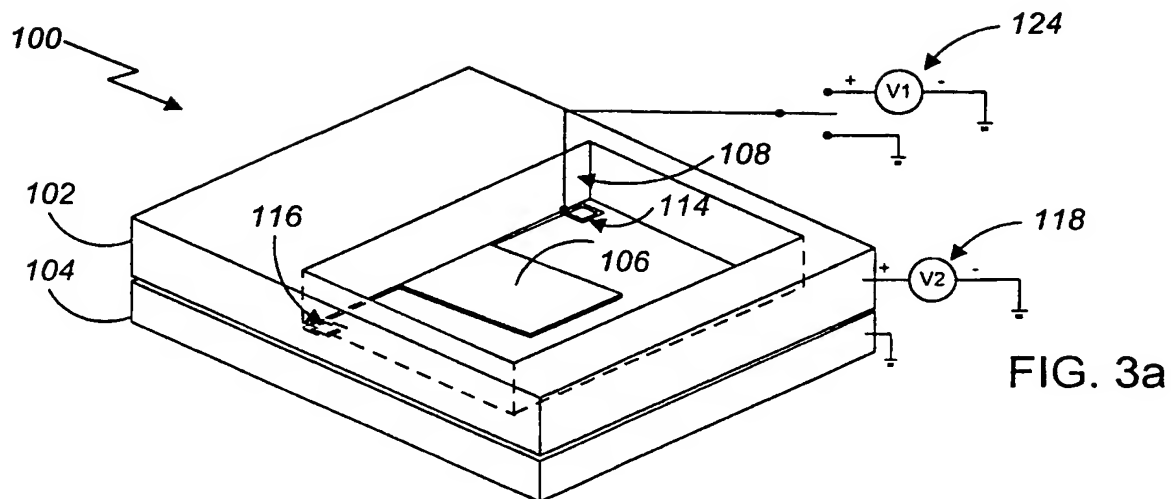
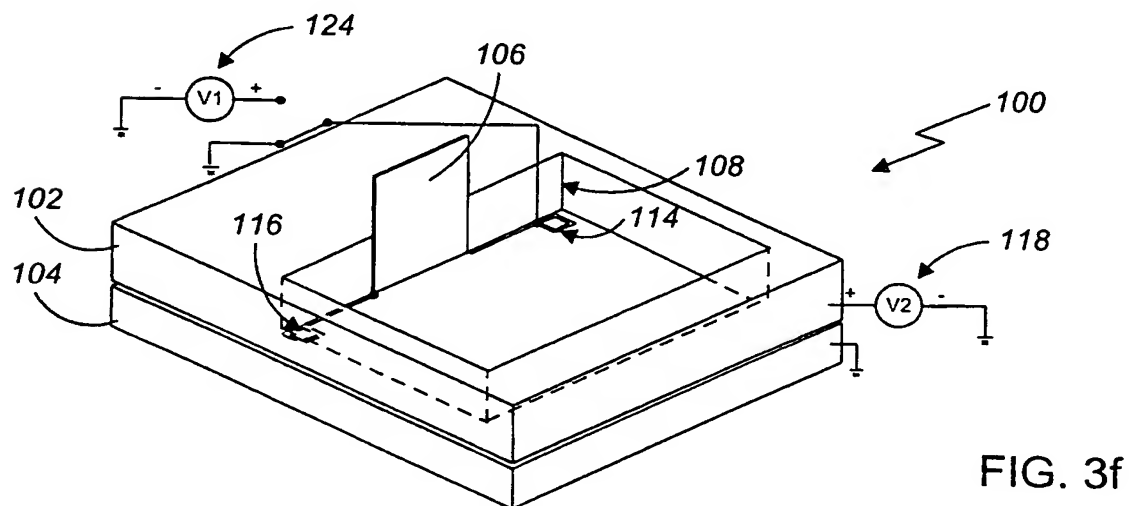
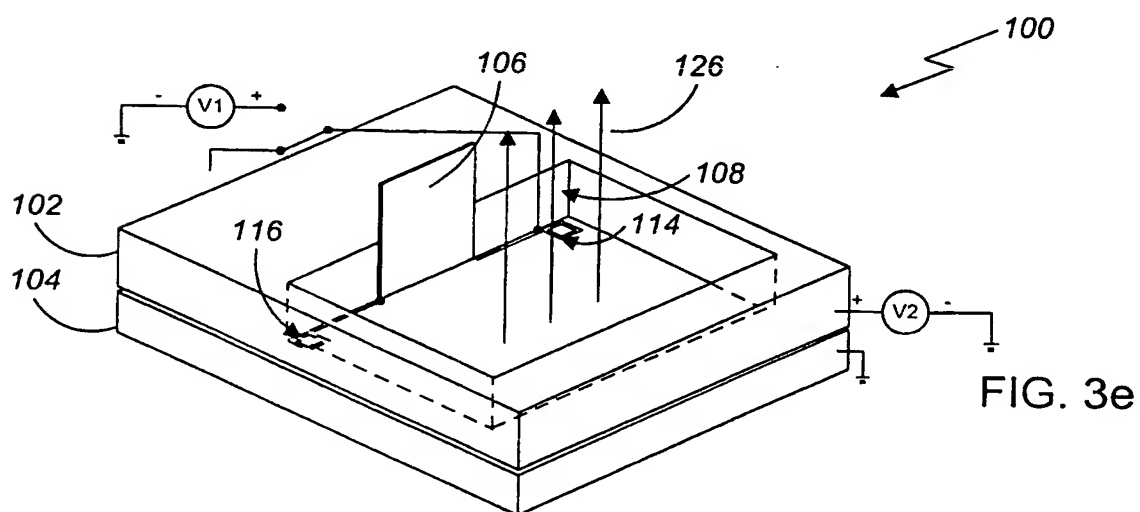
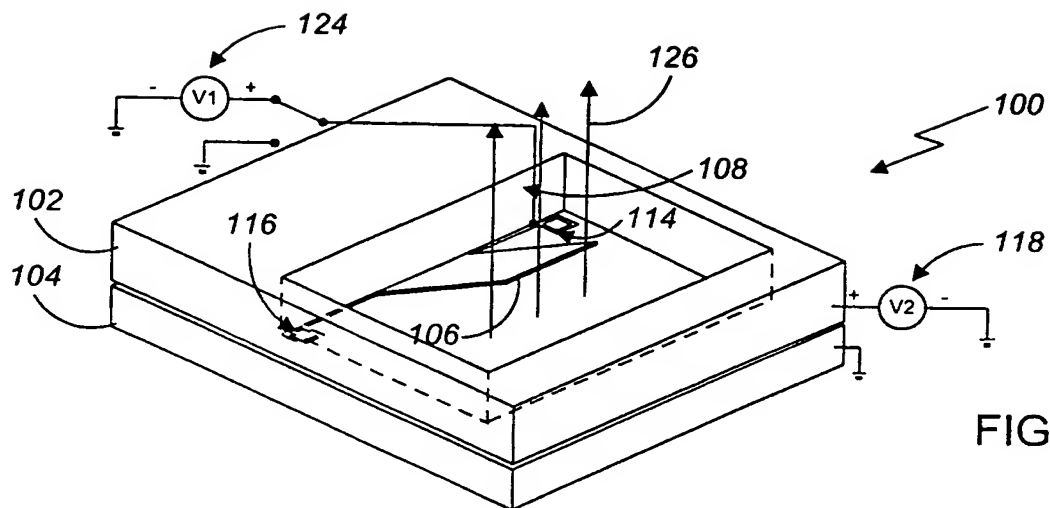


FIG. 2b
(side view)



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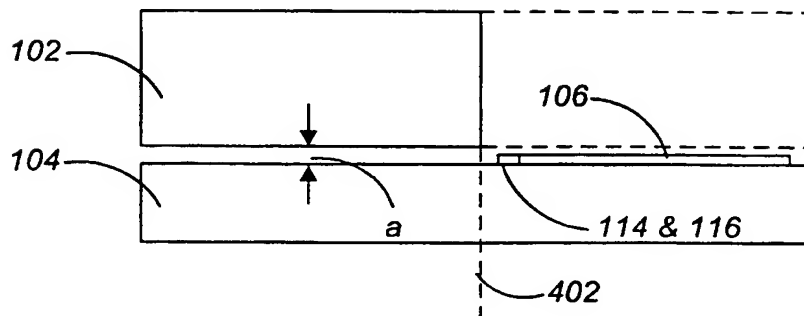


FIG. 4a

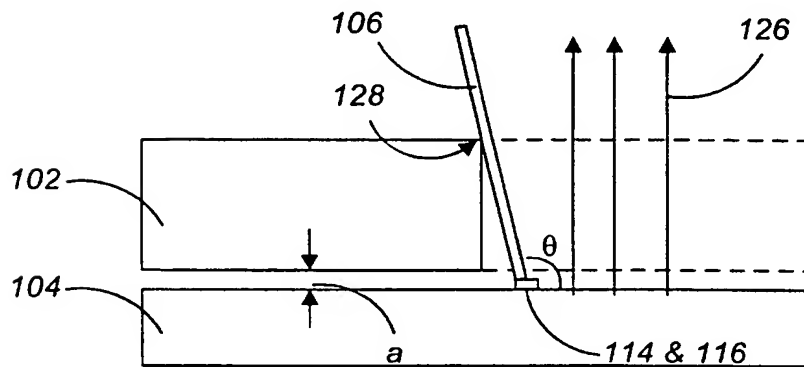


FIG. 4b

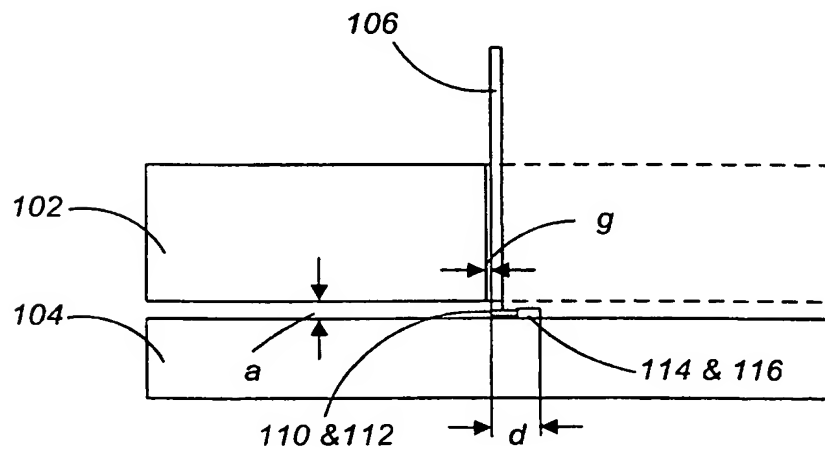


FIG. 4c
(side view)

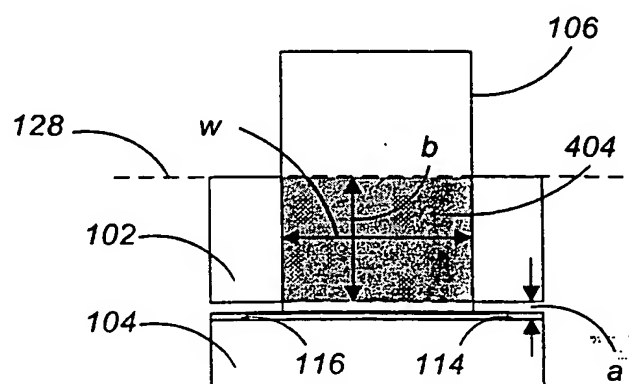


FIG. 4d
(front view)

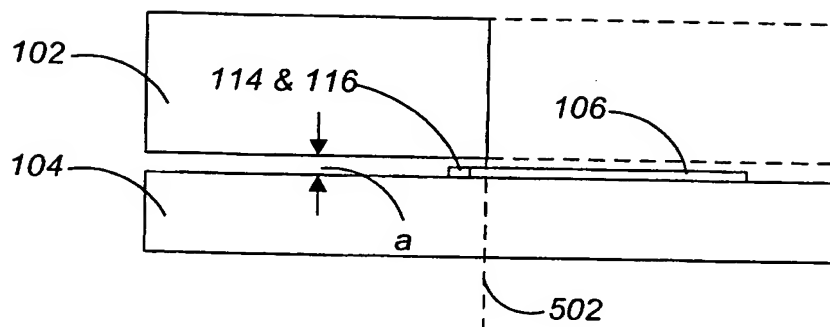


FIG. 5a

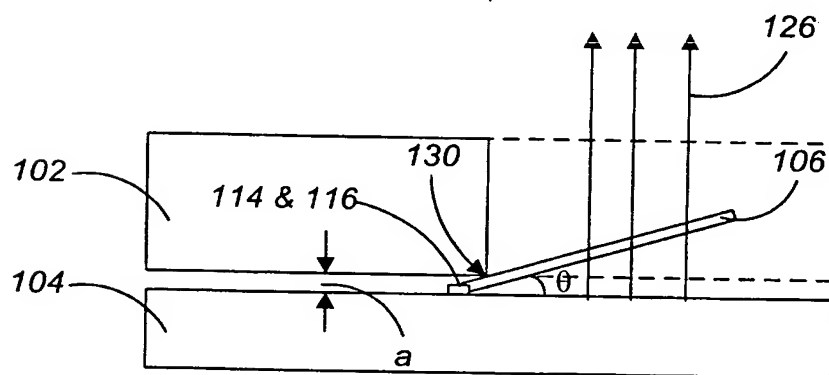


FIG. 5b

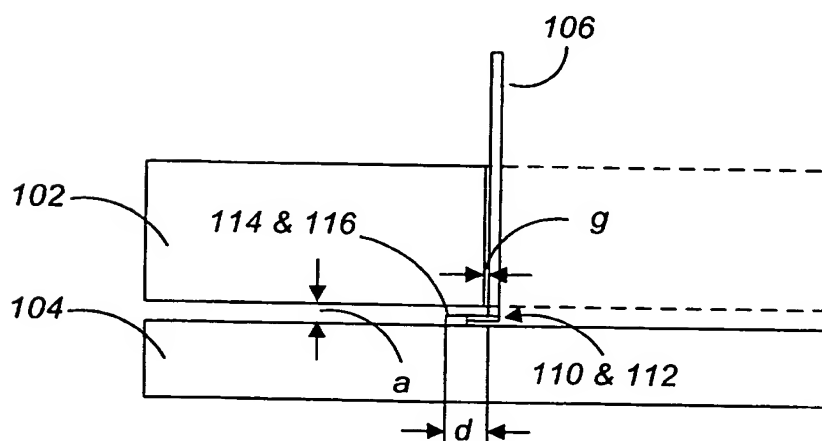


FIG. 5c

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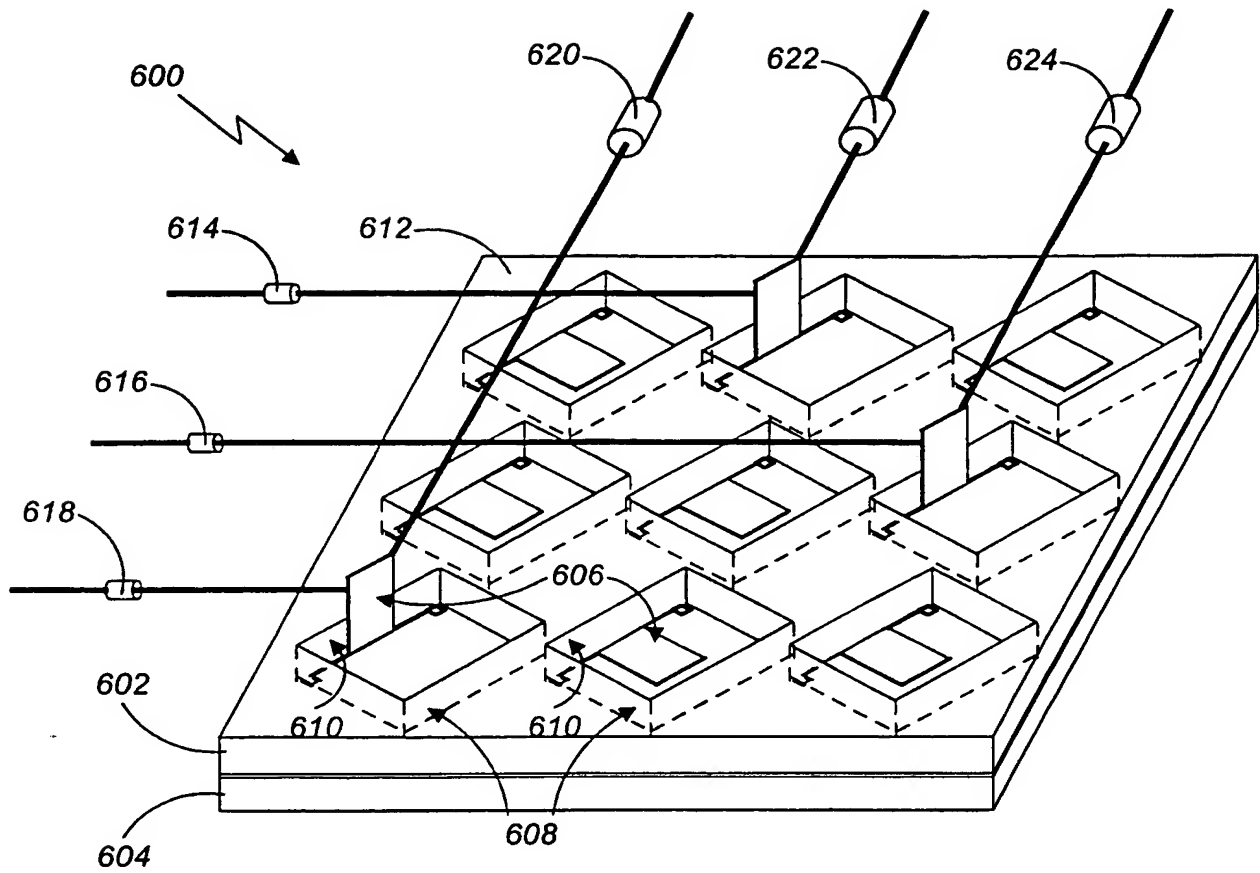
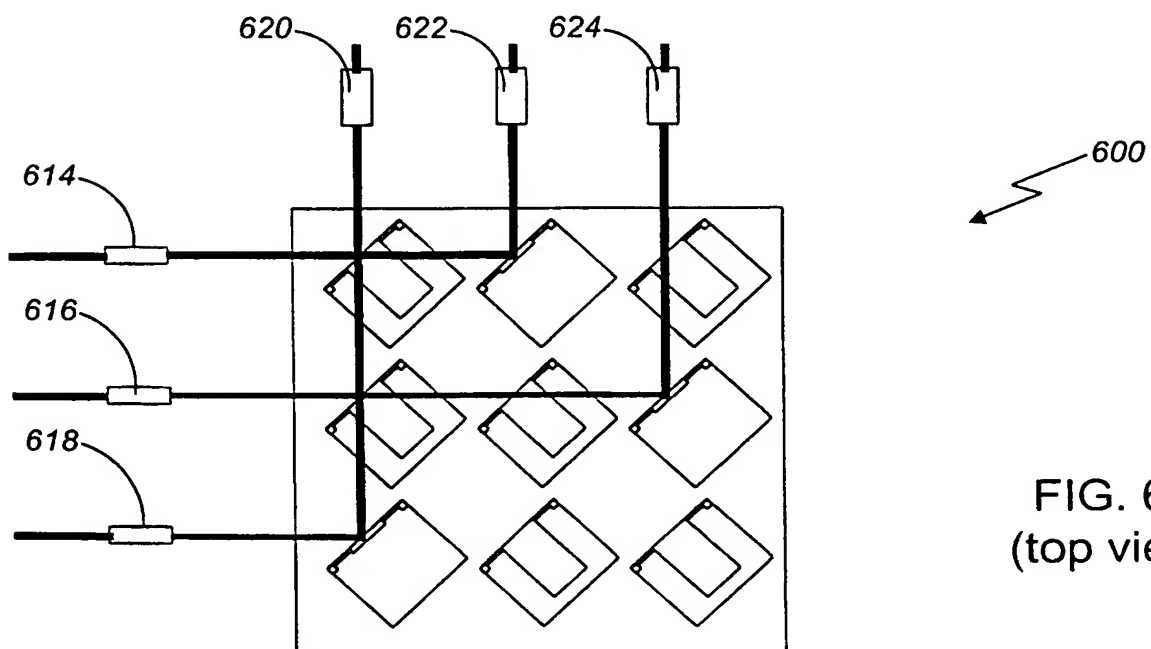


FIG. 6a

FIG. 6b
(top view)

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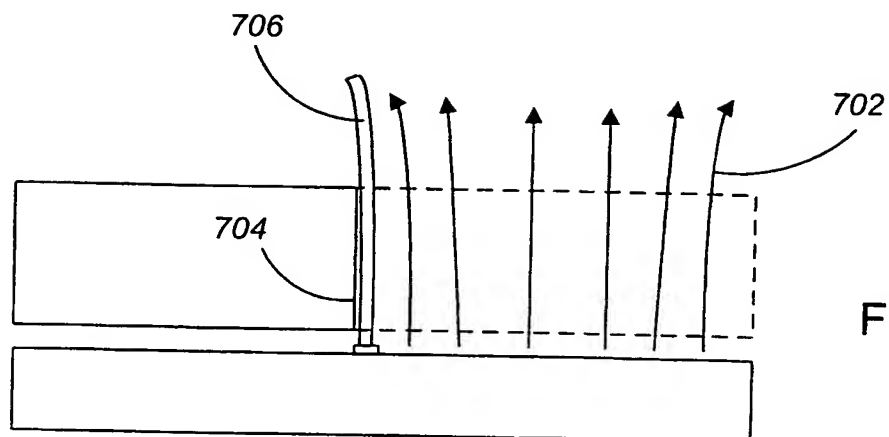


FIG. 7a

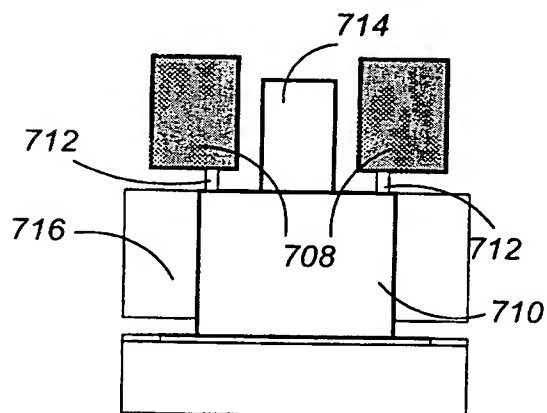


FIG. 7b

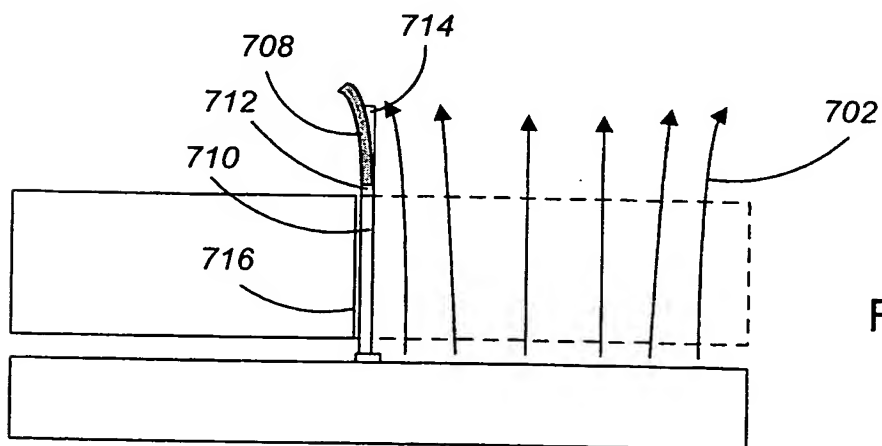


FIG. 7c

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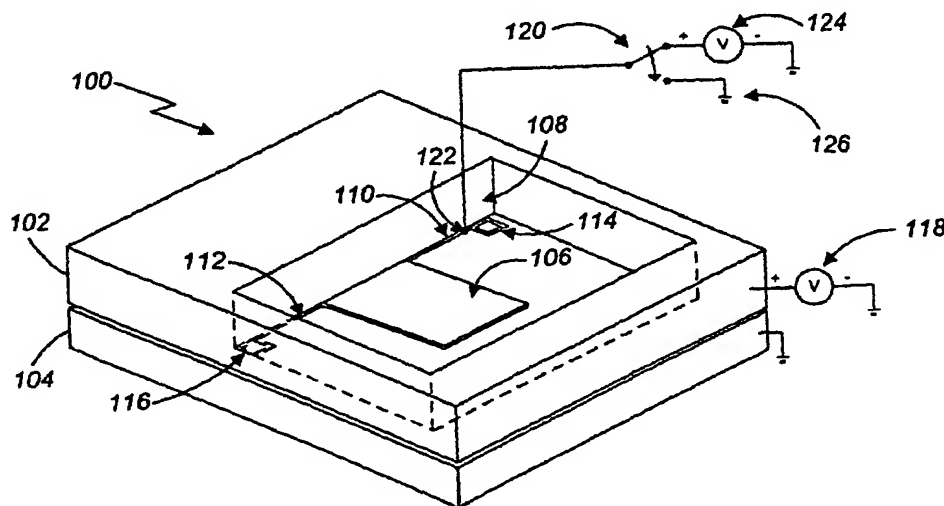
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[Continued on next page]

(54) Title: **CANTILEVERED MICROSTRUCTURE METHODS AND APPARATUS**



(57) Abstract: Cnantilevered microstructure apparatus and methods are described. An exemplary cantilevered microstructure apparatus includes a base, a cantilever, and a stop. The cantilever may be coupled to the base through a flexure, so that the cantilever is movable between a first angular orientation and a second angular orientation. The stop may be configured to contact the bottom portion of the cantilever in a contact area when the cantilever is in the second angular orientation. Alternatively, the stop may be configured to contact the cantilever in a contact area sized so that, upon application of an electrostatic bias between the cantilever and the stop, a sufficient force holds the cantilever against the stop. Alternatively, the stop may have a substantially planar surface configured to contact the cantilever in a contact area sized so that, upon application of a force to the cantilever substantially normal to the substantially planar surface of the stop, a sufficient force holds the cantilever against the stop such that the cantilever lies in a plane substantially parallel to the substantially planar surface of the stop.

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B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)
IPC 7 G02B

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

EPO-Internal, PAJ, INSPEC, IBM-TDB, WPI Data

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	<p>LIN L Y ET AL: "FREE-SPACE MICROMACHINED OPTICAL SWITCHES WITH SUBMILLISECOND SWITCHING TIME FOR LARGE-SCALE OPTICAL CROSSCONNECTS" IEEE PHOTONICS TECHNOLOGY LETTERS,US,IEEE INC. NEW YORK, vol. 10, no. 4, 1 April 1998 (1998-04-01), pages 525-527, XP000754214 ISSN: 1041-1135 See section II:"Design and Fabrication"</p> <p style="text-align: center;">--- -/--</p>	1-42

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Date of the actual completion of the international search

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C.(Continuation) DOCUMENTS CONSIDERED TO BE RELEVANT

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	<p>LAU K Y: "MEM'S THE WORD FOR OPTICAL BEAM MANIPULATION"</p> <p>IEEE CIRCUITS AND DEVICES MAGAZINE, IEEE INC. NEW YORK, US,</p> <p>vol. 13, no. 4, July 1997 (1997-07), pages 11-18, XP000831634</p> <p>ISSN: 8755-3996</p> <p>figures 1,2,14</p> <p style="text-align: center;">---</p>	1-42
X	<p>JAECKLIN V P ET AL: "MECHANICAL AND OPTICAL PROPERTIES OF SURFACE MICROMACHINED TORSIONAL MIRRORS IN SILICON, POLYSILICON AND ALUMINUM"</p> <p>SENSORS AND ACTUATORS A, CH, ELSEVIER SEQUOIA S.A., LAUSANNE,</p> <p>vol. A43, no. 1/03,</p> <p>1 May 1994 (1994-05-01), pages 269-275, XP000454122</p> <p>ISSN: 0924-4247</p> <p>see section "Fabrication"</p> <p style="text-align: center;">---</p>	1-42
X	<p>US 5 774 604 A (MCDONALD TERRANCE G)</p> <p>30 June 1998 (1998-06-30)</p> <p>column 2, line 23 -column 3, line 26</p> <p style="text-align: center;">-----</p>	1-42

INTERNATIONAL SEARCH REPORT

Information on patent family members

International Application No.

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Patent document cited in search report	Publication date	Patent family member(s)	Publication date
US 5774604 A	30-06-1998	NONE	
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